



A Product Line of Diodes Incorporated



Features

- BV_{CEO} > 75V
- I_c = 3A high Continuous Current
- I_{CM} = 10A Peak Pulse Current
- High Gain Holds up h_{FE} > 300 @ I_C=1A
- Low Equivalent On-Resistance; R_{CE(sat)} = 78mΩ at 4.5A
- Excellent hFE characteristics up to 10A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

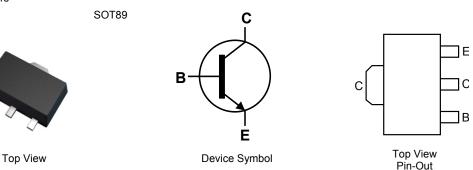
Applications

- Emergency Lighting Circuits
- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- Power Switches
- MOSFET Gate Drivers



Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.052 grams (Approximate)



Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX1053ATA	053	7	12	1,000
FCX1053A-13R	053	13	12	4,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

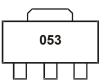
2. See http://www and Lead-free

Notes:

and Leau-nee. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



053 = Product Type Marking Code





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	75	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	A
Base Current	IB	500	mA
Peak Pulse Current	I _{CM}	10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	PD	1.6	W	
	(Note 7)		2.0	1	
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{0JA}	78	°C/W	
	(Note 7)		62.5		
Thermal Resistance, Junction to Lead	(Note 8)	R _{θJL}	3.6	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

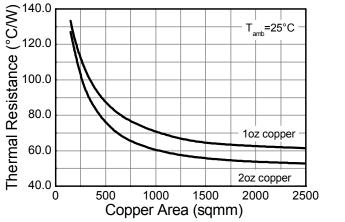
6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

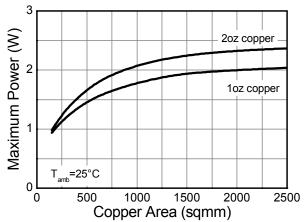
7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.

8. Thermal resistance from junction to solder-point (on the exposed collector pad).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

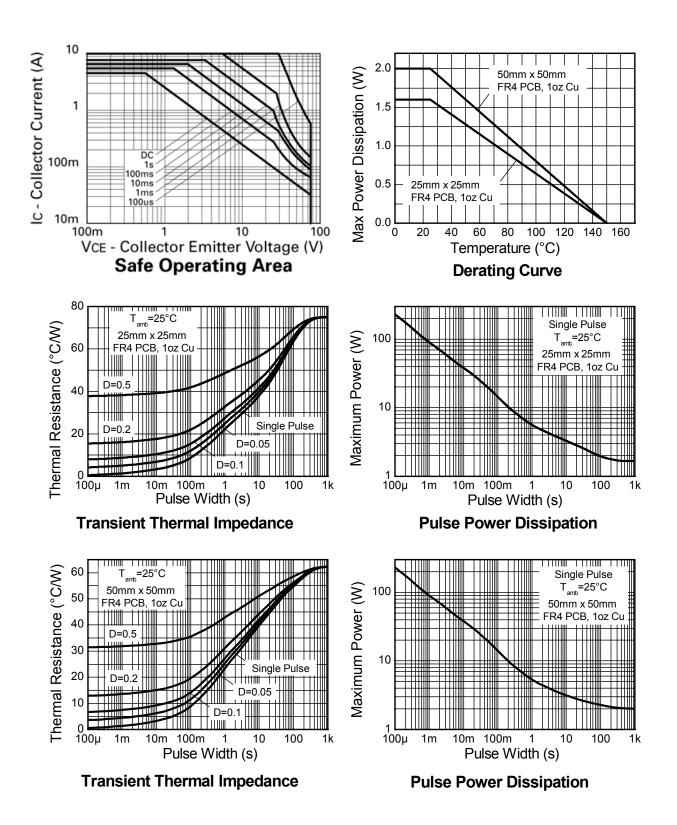
Thermal Characteristics and Derating Information













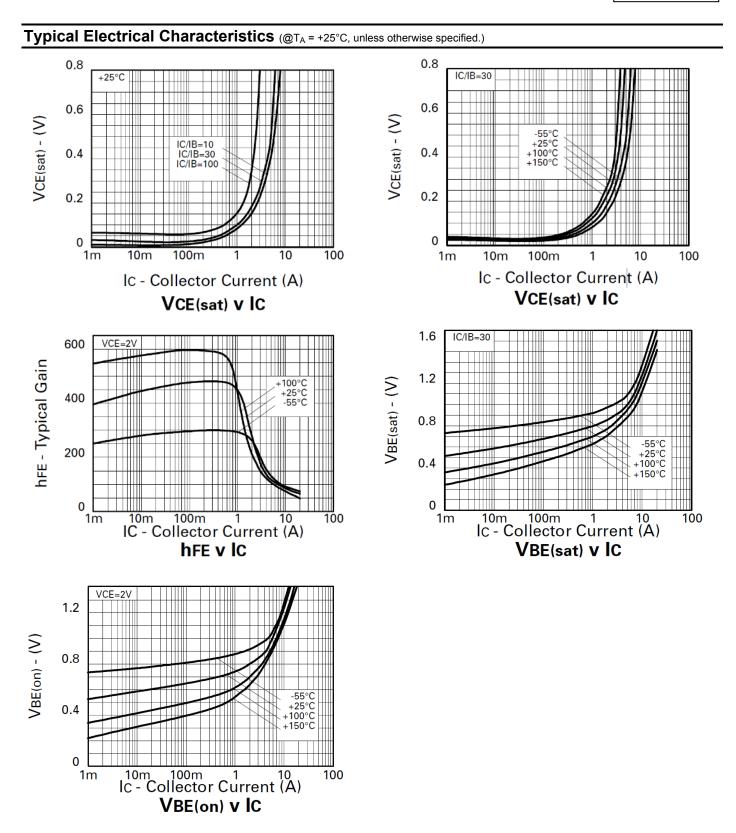


Electrical Characteristics (@T _A = +25°C, unless otherwise specified.)						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	250	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CES}	150	250	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Notes 10)	BV _{CEO}	75	100	—	V	I _C = 10mA
Collector-Emitter Breakdown Voltage	BVCEV	150	250	—	V	I _C = 100μA, V _{EB} = 1V
Emitter-Base Breakdown Voltage	BVEBO	7	8.8	_	V	I _E = 100μA
Collector Cutoff Current	Ісво	_	0.9	50	nA	V _{CB} = 120V
Collector Cutoff Current	I _{CES}	_	1.5	50	nA	V _{CES} = 120V
Emitter Cutoff Current	I _{EBO}	—	0.3	20	nA	V _{EB} = 5.6V
DC current transfer Static ratio (Notes 10)	h _{FE}	270 300 300 40	440 450 450 60 20	1200		$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 0.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 4.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 10 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Notes 10)	V _{CE(sat)}	_	21 55 150 160 350	30 75 200 210 440	mV	$\begin{split} I_{C} &= 0.2A, \ I_{B} = 20mA \\ I_{C} &= 0.5A, \ I_{B} = 20mA \\ I_{C} &= 1A, \ I_{B} = 10mA \\ I_{C} &= 2A, \ I_{B} = 100mA \\ I_{C} &= 4.5A, \ I_{B} = 200mA \end{split}$
Base-Emitter Saturation Voltage (Notes 10)	V _{BE(sat)}	_	900	1000	mV	I _C = 3A, I _B = 100mA
Base-Emitter Turn-on Voltage (Notes 10)	V _{BE(on)}	—	825	950	mV	$I_{C} = 3A, V_{CE} = 2V$
Transitional Frequency	fT	_	140	_	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Output capacitance	C _{obo}	_	21	30	pF	V _{CB} = 10V, f = 1MHz,
Switching Time	t _{on}		162		ns	V _{CC} = 50V, I _C = 2A,
Switching Time	t _{off}] —	900] —	ns	$I_{B1} = I_{B2} = \pm 20 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.





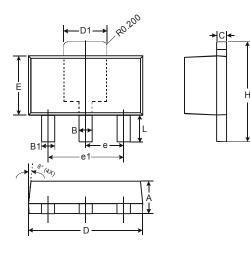






Package Outline Dimensions

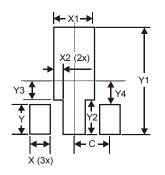
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min Max			
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
ш	2.29	2.60		
е	e 1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89 1.20			
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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